National Semiconductor

LM567/LM567C Tone Decoder

General Description

The LM567 and LM567C are general purpose tone decoders designed to provide a saturated transistor switch to ground when an input signal is present within the passband. The circuit consists of an I and Q detector driven by a voltage controlled oscillator which determines the center frequency of the decoder. External components are used to independently set center frequency, bandwidth and output delay.

Features

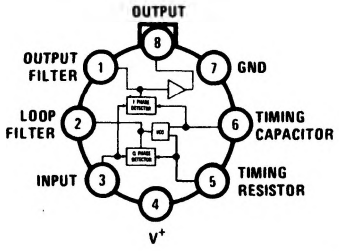
- 20 to 1 frequency range with an external resistor
- Logic compatible output with 100 mA current sinking capability
- Bandwidth adjustable from 0 to 14%
- High rejection of out of band signals and noise
- Immunity to false signals
- Highly stable center frequency
- Center frequency adjustable from 0.01 Hz to 500 kHz

Applications

- Touch tone decoding
- Precision oscillator
- Frequency monitoring and control
- Wide band FSK demodulation
- Ultrasonic controls
- Carrier current remote controls
- Communications paging decoders

Connection Diagrams

Metal Can Package

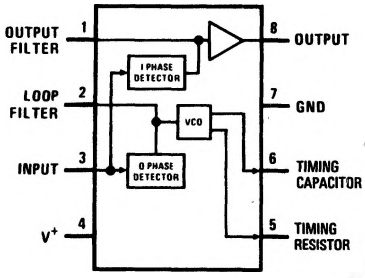


TL/H/6975–1

Top View

Order Number LM567H or LM567CH
See NS Package Number H08C

Dual-In-Line and Small Outline Packages



TL/H/6975–2

Top View

Order Number LM567CM
See NS Package Number M08A

Order Number LM567CN
See NS Package Number N08E

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Pin	9V
Power Dissipation (Note 1)	1100 mW
V_8	15V
V_3	−10V
V_3	V_4 + 0.5V
Storage Temperature Range	−65°C to +150°C
Operating Temperature Range	
LM567H	−55°C to +125°C
LM567CH, LM567CM, LM567CN	0°C to +70°C

Soldering Information

Dual-In-Line Package	
Soldering (10 sec.)	260°C
Small Outline Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

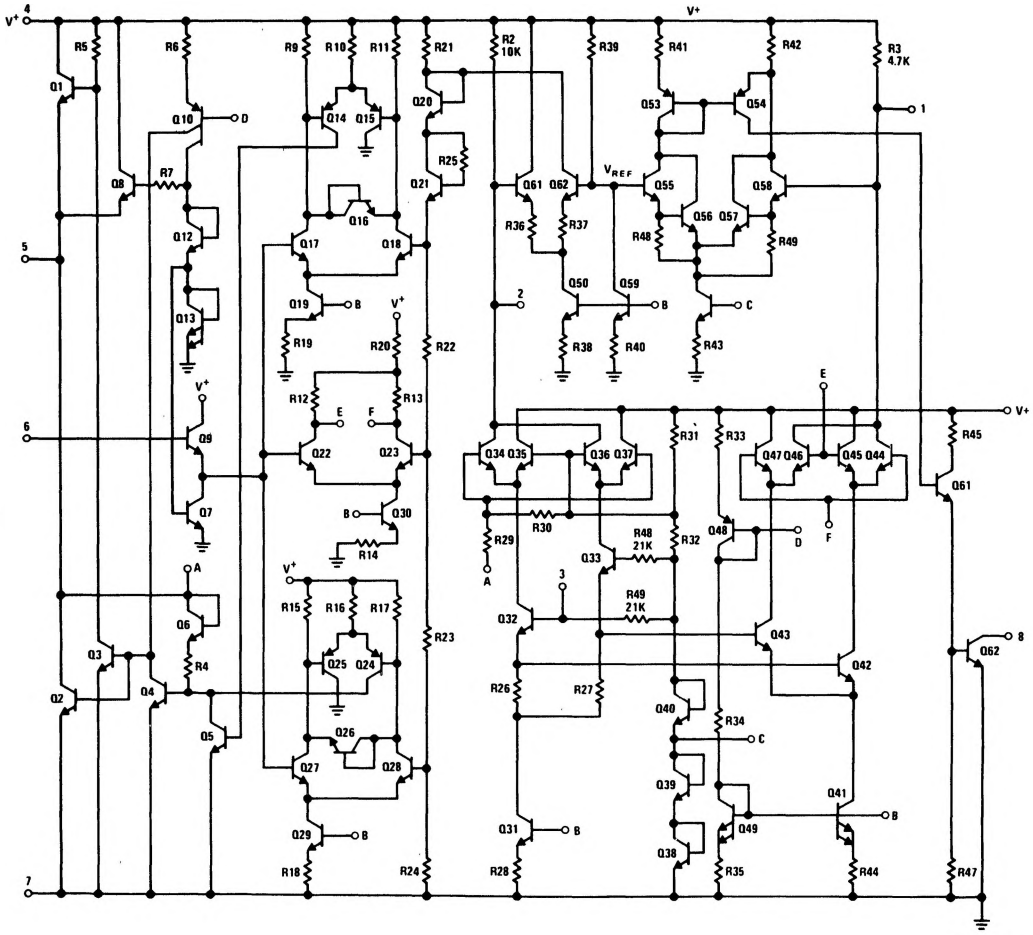
Electrical Characteristics AC Test Circuit, T_A = 25°C, V^+ = 5V

Parameters	Conditions	LM567			LM567C/LM567CM			Units
		Min	Typ	Max	Min	Typ	Max	
Power Supply Voltage Range		4.75	5.0	9.0	4.75	5.0	9.0	V
Power Supply Current Quiescent	R_L = 20k		6	8		7	10	mA
Power Supply Current Activated	R_L = 20k		11	13		12	15	mA
Input Resistance		18	20		15	20		kΩ
Smallest Detectable Input Voltage	I_L = 100 mA, $f_i = f_o$		20	25		20	25	mVrms
Largest No Output Input Voltage	I_C = 100 mA, $f_i = f_o$	10	15		10	15		mVrms
Largest Simultaneous Outband Signal to Inband Signal Ratio			6			6		dB
Minimum Input Signal to Wideband Noise Ratio	B_n = 140 kHz		−6			−6		dB
Largest Detection Bandwidth		12	14	16	10	14	18	% of f_o
Largest Detection Bandwidth Skew			1	2		2	3	% of f_o
Largest Detection Bandwidth Variation with Temperature			±0.1			±0.1		%/°C
Largest Detection Bandwidth Variation with Supply Voltage	4.75 − 6.75V		±1	±2		±1	±5	%V
Highest Center Frequency		100	500		100	500		kHz
Center Frequency Stability (4.75–5.75V)	$0 < T_A < 70$ $-55 < T_A < +125$		35 ± 60 35 ± 140			35 ±60 35 ± 140		ppm/°C ppm/°C
Center Frequency Shift with Supply Voltage	4.75V − 6.75V 4.75V − 9V		0.5	1.0 2.0		0.4	2.0 2.0	%/V %/V
Fastest ON-OFF Cycling Rate			f_o/20			f_o/20		
Output Leakage Current	V_8 = 15V		0.01	25		0.01	25	μA
Output Saturation Voltage	e_i = 25 mV, I_8 = 30 mA e_i = 25 mV, I_8 = 100 mA		0.2 0.6	0.4 1.0		0.2 0.6	0.4 1.0	V
Output Fall Time			30			30		ns
Output Rise Time			150			150		ns

Note 1: The maximum junction temperature of the LM567 and LM567C is 150°C. For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of 150°C/W, junction to ambient or 45°C/W, junction to case. For the DIP the device must be derated based on a thermal resistance of 110°C/W, junction to ambient. For the Small Outline package, the device must be derated based on a thermal resistance of 160°C/W, junction to ambient.

Note 2: Refer to RETS567X drawing for specifications of military LM567H version.

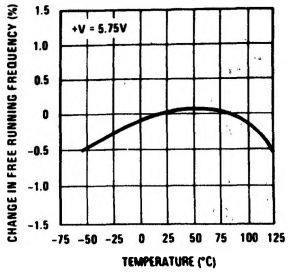
Schematic Diagram



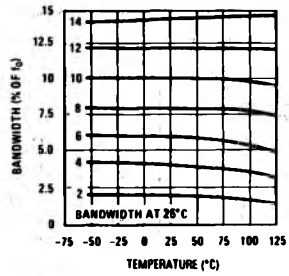
TL/H/6975–3

Typical Performance Characteristics

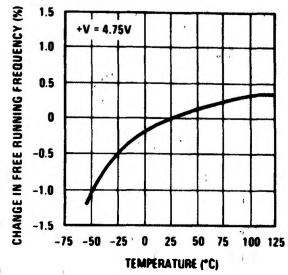
Typical Frequency Drift



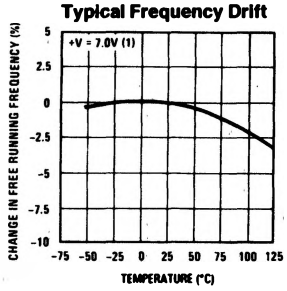
Typical Bandwidth Variation



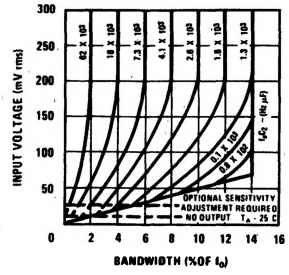
Typical Frequency Drift



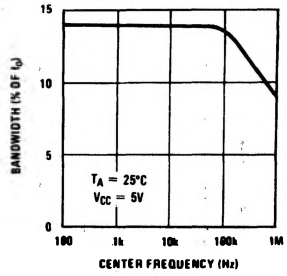
Typical Frequency Drift



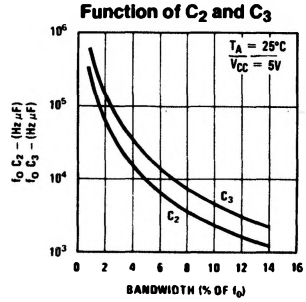
Bandwidth vs Input Signal Amplitude



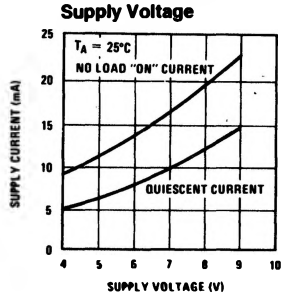
Largest Detection Bandwidth



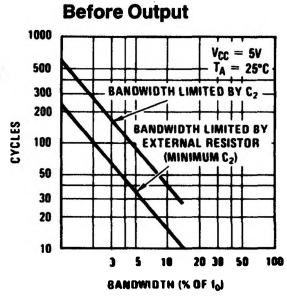
Detection Bandwidth as a Function of C_2 and C_3



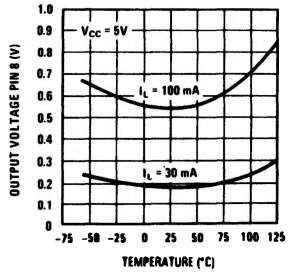
Typical Supply Current vs Supply Voltage



Greatest Number of Cycles Before Output



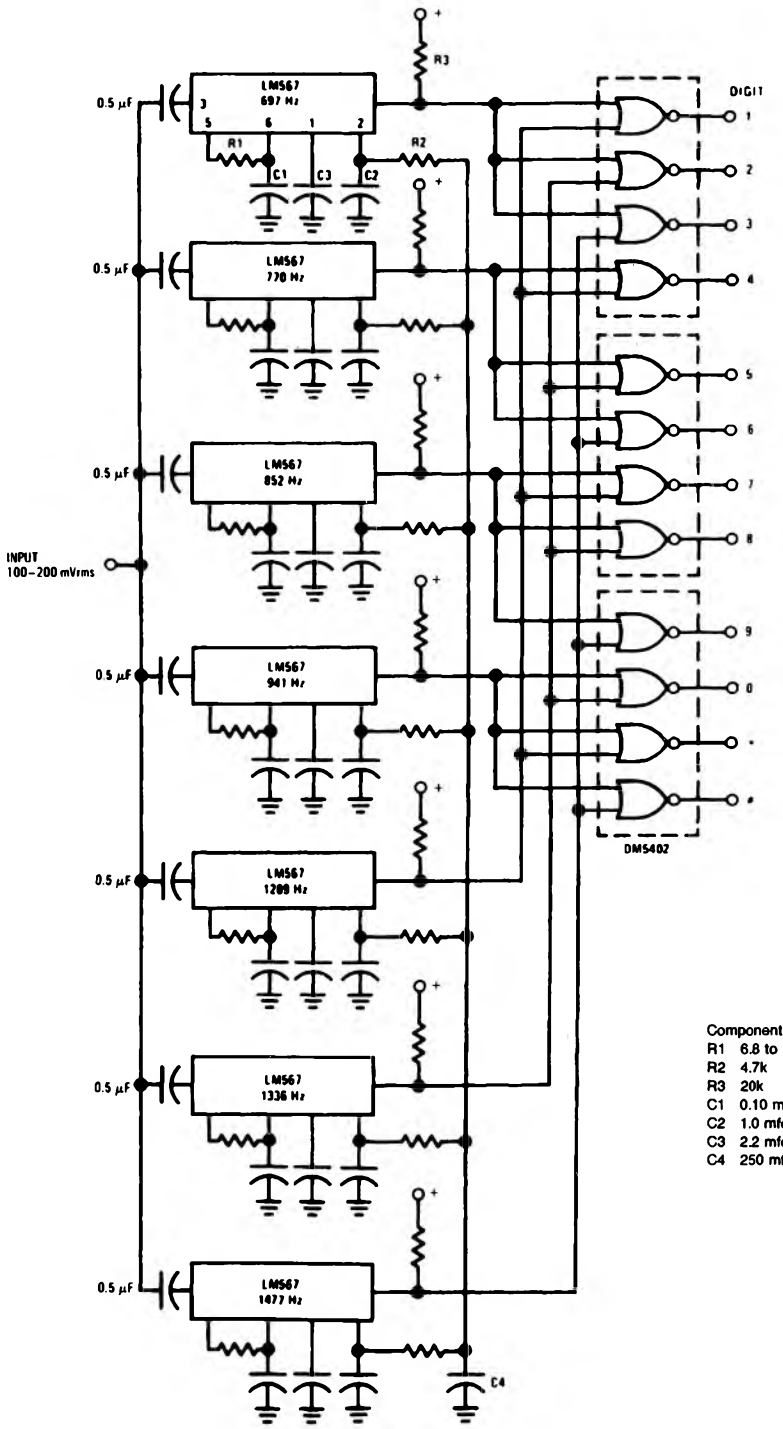
Typical Output Voltage vs Temperature



TL/H/6975–4

Typical Applications

Touch-Tone Decoder



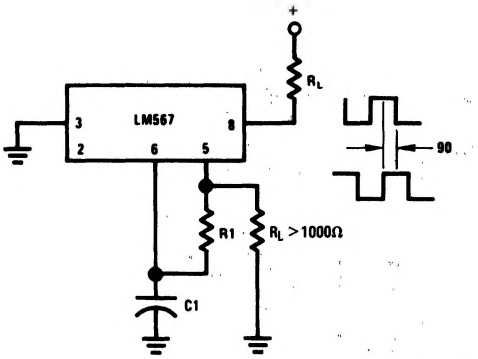
Component values (typ)

R1	6.8 to 15k
R2	4.7k
R3	20k
C1	0.10 mfd
C2	1.0 mfd 6V
C3	2.2 mfd 6V
C4	250 mfd 6V

TL/H/6975–5

Typical Applications (Continued)

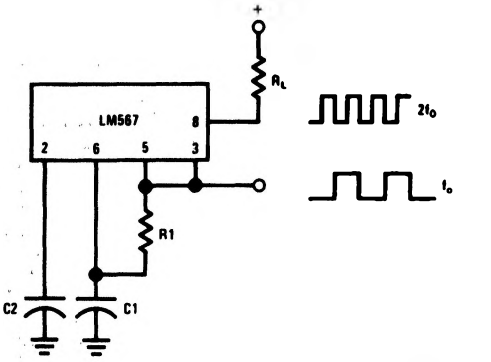
Oscillator with Quadrature Output



TL/H/6975–6

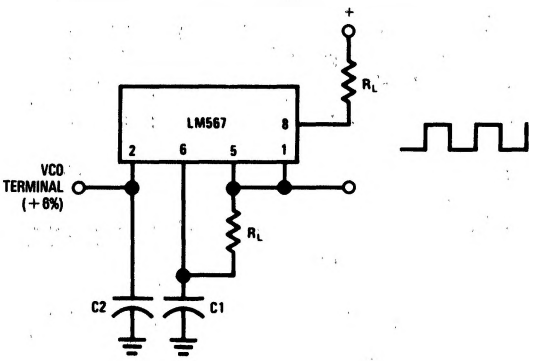
Connect Pin 3 to 2.8V to Invert Output

Oscillator with Double Frequency Output



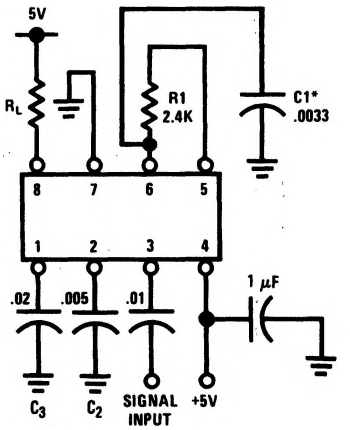
TL/H/6975–7

Precision Oscillator Drive 100 mA Loads



TL/H/6975–8

AC Test Circuit



TL/H/6975–9

f_i = 100 kHz + 5V

*Note: Adjust for f_o = 100 kHz.

Applications Information

The center frequency of the tone decoder is equal to the free running frequency of the VCO. This is given by

$$f_o \cong \frac{1}{1.1\, R_1 C_1}$$

The bandwidth of the filter may be found from the approximation

$$BW = 1070 \sqrt{\frac{V_i}{f_o C_2}} \text{ in \% of } f_o$$

Where:

V_i = Input voltage (volts rms), $V_i \leq 200$ mV

C_2 = Capacitance at Pin 2 (μF)